Calendar

To list an event in the Calendar, contact Julia Phillips, AT&T Bell Laboratories, 600 Mountain Avenue IE-431, Murray Hill, NJ 07974; telephone (201) 582-4428.

MRS indicates the meeting is sponsored by or affiliated with the Materials Research Society.

DECEMBER 1985

- 2-6 MRS Fall Meeting of the Materials Research Society.
 Boston, MA.
 J. B. Ballance,
 Materials Research Society,
 9800 McKnight Rd., Suite 327,
 Pittsburgh, PA 15237;
 (412) 367-3003.
- 18-20 Solid State Physics Conference. University of Reading. Inst. of Physics, 47 Belgrave Sq., London SW1X 8QX, U.K.; 01-235-6111

JANUARY 1986

- 19-24 Symposium on Optical and Electro-Optical Engineering.
 Los Angeles, CA.
 SPIE, P.O. Box 10, Bellingham, WA 98227-0010; (206) 676-3290.
- 27-28 Conference on III-V and II-VI Compound Semiconductor Surfaces: Structure, Composition, and Electrical Properties.
 Atlanta, GA.
 Microelectronics Research Center, Building 0250, GA Institute of Technology, Atlanta, GA 30332; (404) 894-2928.

FEBRUARY 1986

9-12 9th Annual Meeting of the Adhesion Society.
Hilton Head, SC.
J. P. Wightman, VPE, Chemistry Dept., Blacksburg, VA 24061; (703) 961-5854.

MARCH 1986

- 9-14 SPIE Symposium on Microlithography. Santa Clara, CA. SPIE Technical Program Committee, P.O. Box 10, Bellingham, WA 98227-0010; (206) 676-3290.
- 22-25 Conference of the Condensed Matter Division of the European Physical Society.
 Stockholm, Sweden.
 G. Grimvall, Dept. of Theoretical Physics, Royal Inst. of Technology, S-100 44 Stockholm, Sweden.
- 31-4 General Meeting of the APS. Las Vegas, CA. W. W. Havens, 335 E. 45th St., New York, NY 10017
- 31-5 Optical Society of America 1986 Spring Meeting. Honolulu, Hawaii. OSA, 1816 Jefferson Pl., N.W., Washington, DC 20036

APRIL 1986

- International Conference on Metallurgical Coatings.
 San Diego, CA.
 H. A. Beale, Applied Coatings International, 775 Kaderly Dr., Columbus, OH 43228
- 7-10 MRS Low Energy Ion
 Beams—4.
 Brighton, England.
 The Institute of Physics, 47
 Belgrave Square, London
 SW1X 8QX, England;
 01-235-6111.
 (See related article in Vol. X No. 5.)
- 8-10 31st National SAMPE Symposium—Materials Science for the Future. Las Vegas, CA. Marge Smith, SAMPE, P.O. Box 2459, Covina, CA 91722: (818) 331-0616

- 13-18 American Chemical Society General Meeting. New York, NY. American Chemical Society, 1155 16th St., N.W., Washington, DC 20036.
- 15-18 MRS Spring Meeting of the Materials Research Society.
 Palo Alto, CA.
 J. B. Ballance,
 Materials Research Society,
 9800 McKnight Rd., Suite 327,
 Pittsburgh, PA 15237;
 (412) 367-3003.
- 27-1 American Ceramic Society General Meeting.
 Chicago, IL
 American Ceramic Society, 65
 Ceramic Dr., Columbus, OH 43214.

MAY 1986

- 1-2 MRS Semiconductor Based Heterostructures: Interface Structure and Stability (1986 TMS Northeast Regional Conference).
 Murray Hill, NJ.
 Martin L. Green, AT&T Bell Laboratories, Murray Hill, NJ; (201) 582-3000.
- 4-9 Spring Meeting of the Electrochemical Society. Boston, MA. Electrochemical Society, 10 S. Main St., Pennington, NJ 08534-2896.
- 4-9 Fifth International Symposium on Silicon Materials Science & Technology.
 Boston, MA.
 H. R. Huff, Monsanto Electronic Materials Company, 755 Page Mill Rd. P.O. Box 10123, Palo Alto, CA 94303
- 27-30 International Conference on Composite Interfaces.
 Cleveland, OH.
 H. Ishida, Dept. of Macromolecular Sci., Case Western Reserve Univ., Cleveland, OH 44106; (216) 368-4285.

(continued on the next page

JUNE 1985

9-13 MRS International Conference on Ion Beam Modification of Materials.

Catania, Italy. E. Rimini, Depart. of Physics, Corso Italia 57, 195129 Catania, Italy.

- 9-13 OSA/IEEE Conference on Laser & Electro-Optics (CLEO '86).
 San Francisco, CA.
 Optical Society of America, 1816
 Jefferson Pl., N.W., Washington,
 DC 20036
- 9-13 International Conference on Quantum Electronics.
 San Francisco, C.A.
 Optical Society of America, 1816
 Jefferson Pl., N.W., Washington,
 DC 20036;
 (202) 223-0920.
- 10-12 7th International SAMPE
 European Chapter Conference &
 Exhibition.
 Munich, Germany.
 SAMPE, 843 West Glentana (Box 2459), Covina, CA 91722;
 (818) 331-0616

(See related article in Vol. X No. 5.)

JULY 1986

- 7-11 Fifth International Conference on Surface Modification of Metals of Ion Beams.
 Kingston, Ontario.
 J. L. Whitton, Physics Dept.
 Queens Univ., Kingston, ONT
 K7L 3N6: (613) 547-2746.
- 28-31 International Conference on Ceramic Microstructures '86: Role of Interfaces.
 University of California, Berkeley, CA.
 Joseph A. Pask, Dept. of Materials Science and Mineral Engineering, University of California, Berkeley, CA; (415) 642-3801.
- 28-1 Second International Conference on Shallow Impurity Centres. Trieste, Italy. Prof. R. Resta, SISSA Strada Costiera 11, 34014 Trieste, Italy; telephone (040) 22 41 18; telex 460392 ICTP I.

AUGUST 1986

- International Conference on Low-Energy Dislocation Structures.
 Charlottesville, VA.
 D. Murdaugh, Dept. of
 Conferences & Institutes, Div. of
 Continuing Education, P.O. Box
 3697, 104 Midmont Ln.,
 Charlottesville, VA 22903; (804)
 924-7141.
- 11-15 18th International Conference on the Physics of Semiconductors.
 Stockholm, Sweden.
 S. T. Pantelides, ICPS-18 Program Subcommittee Chairman, IBM T.
 J. Watson Research Center, P.O.
 Box 218, Yorktown Heights, NY 10598; (914) 945-3000.
- 17-22 30th Annual Symposium on Optical & Electro-Optical Engineering. San Diego, CA. SPIE, P.O. Box 10, Bellingham, WA 98227-0010; (206) 676-3290.
- 18-22 14th International Conference on Defects in Semiconductors.
 Paris, France.
 D. Stievenard, Secretary ICDS 14, ISEN, 3 rue François Baës, 59046, Lille, France.

SEPTEMBER 1986

- 7-10 International Conference on Molecular Beam Epitaxy.
 York, U.K.
 G. J. Davies, British Telecom
 Research Labs, Martlesham
 Heath, Ipswich IP5 7RE, U.K.
- 8-11 16th European Solid State Device Research Conference. Cambridge, UK. Meetings Officer, IOP, 47 Belgrave Sq., London, UK SW1X 8QX.
- 14-19 Symposium on Optical & Electro-Optical Engineering. Cambridge, MA. SPIE, P.O. Box 10, Bellingham, WA 98227-0010.
- 22-27 Eighth International Congress on the Chemistry of Cement. Rio de Janeiro, Brazil. Secretaria Geral-8° Cong. Int. de Quim. do Cimento, Rua da Assembléia, 10, 40° Andar, Grupo 4001, 20.011, Rio de Janeiro, RJ, Brazil.

28-1 13th International Symposium on GaAs and Related Compounds.
Hilton Head, SC.
C. M. Wolfe, Washington Univ.,
Box 1127,
St. Louis, MO 63130.

OCTOBER 1986

7-9 18th National SAMPE Technical Conference.
Seattle, WA.
SAMPE, 843 West Glentana (Box 2459), Covina, CA 91722; (818) 331-0616.

(See related article in Vol. X No. 5.)

- Fall Meeting of the Electrochemical Society.
 San Diego, CA.
 Electrochemical Society,
 10 S. Main St.,
 Pennington, NJ 08534-2896.
- 21-24 Meeting of the Optical Society of America. Los Angeles, CA. OSA, 1816 Jefferson Pl., N.W., Washington, DC 20036.
- 26-31 33rd National Vacuum
 Symposium of the American
 Vacuum Society.
 Baltimore, MD.
 N. Hammond, 335 E. 45th St.,
 New York, NY 10017.

NOVEMBER 1986

3-7 Meeting of the Division of Plasma Physics of the APS. Baltimore, MD. W. W. Havens, 335 E. 45th St., New York, NY 10017.

DECEMBER 1986

1-5 MRS Materials Research
Society Fall Meeting.
Boston, MA.
J. B. Ballance, Materials Research
Society, 9800 McKnight Road,
Suite 327, Pittsburgh, PA 10017.

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